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- Available in 5-V, 4.85-V, and 3.3-V
 Fixed-Output and Adjustable Versions
- Very Low-Dropout Voltage . . . Maximum of 32 mV at I_O = 100 mA (TPS7150)
- Very Low Quiescent Current Independent of Load . . . 285 μA Typ
- Extremely Low Sleep-State Current 0.5 μA Max
- 2% Tolerance Over Specified Conditions For Fixed-Output Versions
- Output Current Range of 0 mA to 500 mA
- TSSOP Package Option Offers Reduced Component Height for Space-Critical Applications
- Power-Good (PG) Status Output

description

The TPS71xx integrated circuits are a family of micropower low-dropout (LDO) voltage regulators. An order of magnitude reduction in dropout voltage and quiescent current over conventional LDO performance is achieved by replacing the typical pnp pass transistor with a PMOS device.

NC – No internal connection † SENSE – Fixed voltage options only (TPS7133, TPS7148, and TPS7150) ‡ FB – Adjustable version only (TPS7101)

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (maximum of 32 mV at an output current of 100 mA for the TPS7150) and is directly proportional to the output current (see Figure 1). Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and remains independent of output loading (typically 285 μ A over the full range of output current, 0 mA to 500 mA). These two key specifications yield a significant improvement in operating life for battery-powered systems. The LDO family also features a sleep mode; applying a TTL high signal to EN (enable) shuts down the regulator, reducing the quiescent current to 0.5 μ A maximum at T₁ = 25°C.



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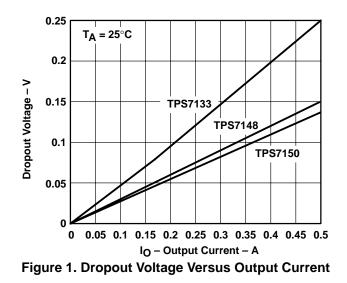


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	R P PAC (TOP VII		
GND (EN (IN (IN (1 2 3 4	8 7 6 5] PG] SENSE†/FB‡] OUT] OUT
-	W PACK (TOP VII		—
GND [1	20] PG
GND	2	19	NC
GND	3	18] NC
NC [4	17] FB‡
NC [5	16] NC
EN [~		
—·· Ц	6	15] SENSE [†]
NC [6 7	15 14] SENSE [†]] OUT
			5
NC [7	14	ΙΟυΤ

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description (continued)



Power good (PG) reports low output voltage and can be used to implement a power-on reset or a low-battery indicator.

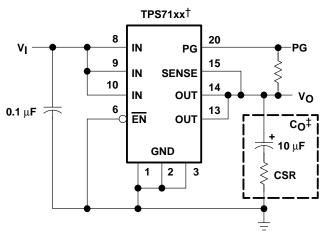
The TPS71xx is offered in 3.3-V, 4.85-V, and 5-V fixed-voltage versions and in an adjustable version (programmable over the range of 1.2 V to 9.75 V). Output voltage tolerance is specified as a maximum of 2% over line, load, and temperature ranges (3% for adjustable version). The TPS71xx family is available in PDIP (8 pin), SO (8 pin), and TSSOP (20-pin) packages. The TSSOP has a maximum height of 1,2 mm.

T.	OUTPU	UT VOLT (V)	AGE	PAG	CKAGED DEVICE	ES	CHIP FORM
Тј	MIN	TYP	MAX	SMALL OUTLINE (D)	PLASTIC DIP (P)	TSSOP (PW)	(Y)
	4.9	5	5.1	TPS7150QD	TPS7150QP	TPS7150QPW	TPS7150Y
	4.75	4.85	4.95	TPS7148QD	TPS7148QP	TPS7148QPW	TPS7148Y
-40°C to 125°C	3.23	3.3	3.37	TPS7133QD	TPS7133QP	TPS7133QPW	TPS7133Y
		ljustable [†] V to 9.75		TPS7101QD	TPS7101QP	TPS7101QPW	TPS7101Y

AVAILABLE OPTIONS

[†]The D and PW packages are available taped and reeled. Add R suffix to device type (e.g., TPS7150QDR). The TPS7101Q is programmable using an external resistor divider (see application information). The chip form is tested at 25°C.



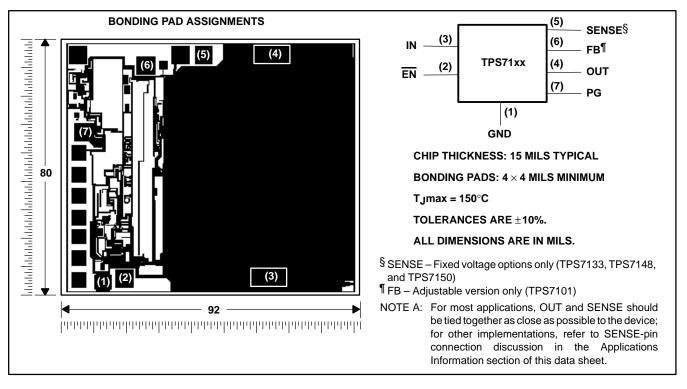


 TPS7133, TPS7148, TPS7150 (fixed-voltage options)
 Capacitor selection is nontrivial. See application information section for details.

Figure 2. Typical Application Configuration

TPS71xx chip information

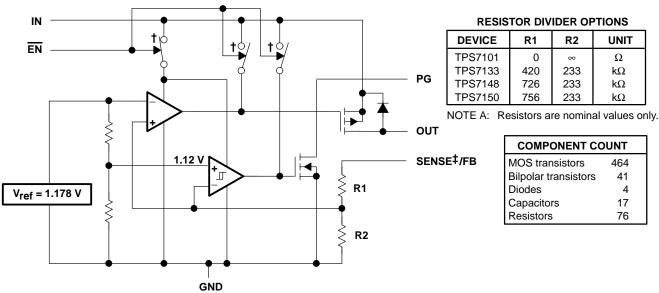
These chips, when properly assembled, display characteristics similar to the TPS71xxQ. Thermal compression or ultrasonic bonding may be used on the doped aluminum bonding pads. The chips may be mounted with conductive epoxy or a gold-silicon preform.





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functional block diagram



[†] Switch positions are shown with \overline{EN} low (active).

[‡] For most applications, SENSE should be externally connected to OUT as close as possible to the device. For other implementations, refer to SENSE-pin connection discussion in Applications Information section.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)§

Input voltage range¶, V _I , PG, SENSE, EN	–0.3 V to 11 V
Output current, I _O	
Continuous total power dissipation	
Operating virtual junction temperature range, T _J	–55°C to 150°C
Storage temperature range, T _{stg} Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	−65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 \P All voltage values are with respect to network terminal ground.

DISSIPATION RATING TABLE 1 – FREE-AIR TEMPERATURE (see Figure 3)#

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	145 mW
Р	1175 mW	9.4 mW/°C	752 mW	235 mW
PWII	700 mW	5.6 mW/°C	448 mW	140 mW

DISSIPATION RATING TABLE 2 – CASE TEMPERATURE (see Figure 4)[#]

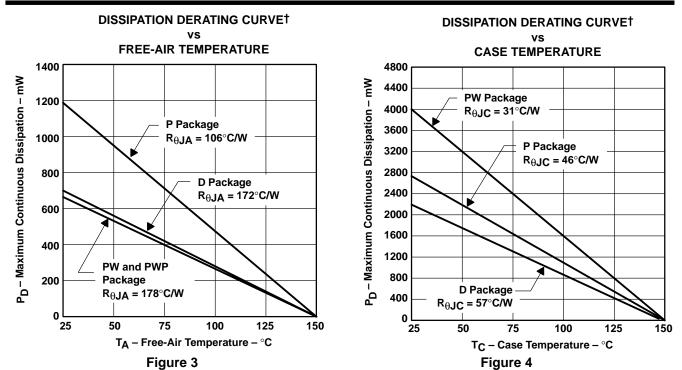
PACKAGE	T _C ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _C = 25°C	T _C = 70°C POWER RATING	T _C = 125°C POWER RATING
D	2188 mW	17.5 mW/°C	1400 mW	438 mW
Р	2738 mW	21.9 mW/°C	1752 mW	548 mW
PWII	4025 mW	32.2 mW/°C	2576 mW	805 mW

[#] Dissipation rating tables and figures are provided for maintenance of junction temperature at or below absolute maximum temperature of 150°C. For guidelines on maintaining junction temperature within recommended operating range, see the Thermal Information section.

Il Refer to Thermal Information section for detailed power dissipation considerations when using the TSSOP packages.



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[†] Dissipation rating tables and figures are provided for maintenance of junction temperature at or below absolute maximum temperature of 150°C. For guidelines on maintaining junction temperature within recommended operating range, see the Thermal Information section.

recommended operating conditions

		MIN	MAX	UNIT
	TPS7101Q	2.5	10	
Input voltage, VI‡	TPS7133Q	3.77	10	V
	TPS7148Q	5.2	10	v
	TPS7150Q	5.33	10	
High-level input voltage at EN, V _{IH}		2		V
Low-level input voltage at \overline{EN} , V _{IL}			0.5	V
Output current range, IO		0	500	mA
Operating virtual junction temperature range	ge, Тј	-40	125	°C

[‡] Minimum input voltage defined in the recommended operating conditions is the maximum specified output voltage plus dropout voltage at the maximum specified load range. Since dropout voltage is a function of output current, the usable range can be extended for lighter loads. To calculate the minimum input voltage for your maximum output current, use the following equation: V_{I(min)} = V_{O(max)} + V_{DO(max load)} Because the TPS7101 is programmable, r_{DS(on)} should be used to calculate V_{DO} before applying the above equation. The equation for calculating V_{DO} from r_{DS(on)} is given in Note 2 in the electrical characteristics table. The minimum value of 2.5 V is the absolute lower limit for the recommended input voltage range for the TPS7101.



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electrical characteristics at I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 µF/CSR[†] = 1 Ω , SENSE/FB shorted to OUT (unless otherwise noted)

PARAMETER	TEST CON	TEST CONDITIONS [‡]		TPS7101Q, TPS7133Q TPS7148Q, TPS7150Q			UNIT	
			Тј	MIN	TYP	MAX	1	
Ground current (active mode)	$\overline{EN} \le 0.5 \text{ V},$	V _I = V _O + 1 V,	25°C		285	350	μA	
Ground current (active mode)	$0 \text{ mA} \leq I_O \leq 500 \text{ mA}$		-40°C to 125°C			460	μΑ	
Input current (standby mode)		07/////////////////////////////////////	25°C			0.5	μA	
input current (standby mode)	$\overline{EN} = V_{I},$	$2.7 \text{ V} \leq \text{V}_{I} \leq 10 \text{ V}$	-40°C to 125°C			2	μΑ	
Output ourroat limit		$\lambda = 10 \lambda$	25°C		1.2	2	A	
Output current limit	V _O = 0,	V _I = 10 V	-40°C to 125°C			2	A	
Pass-element leakage current in standby			25°C			0.5		
mode	EN = V _I ,	$2.7 \text{ V} \le \text{V}_{\text{I}} \le 10 \text{ V}$	-40°C to 125°C			1	μA	
PG leakage current	Normal operation,	Vpg = 10 V	25°C		0.02	0.5		
			-40°C to 125°C			0.5	μA	
Output voltage temperature coefficient			-40°C to 125°C		61	75	ppm/°C	
Thermal shutdown junction temperature					165		°C	
	$2.5 V \le V_1 \le 6 V$		1000 1- 10500	2			V	
EN logic high (standby mode)	$6 \text{ V} \le \text{V}_{I} \le 10 \text{ V}$		-40°C to 125°C	2.7			V	
	071/01/01/01/		25°C			0.5	v	
EN logic low (active mode)	$2.7 \text{ V} \le \text{V}_{I} \le 10 \text{ V}$		-40°C to 125°C			0.5		
EN hysteresis voltage			25°C		50		mV	
			25°C	-0.5		0.5		
EN input current	$0 V \le V_I \le 10 V$	$0 \text{ V} \leq \text{V}_{I} \leq 10 \text{ V}$	-40°C to 125°C	-0.5		0.5	μA	
			25°C		2.05	2.5		
Minimum V _I for active pass element			-40°C to 125°C			2.5	V	
			25°C		1.06	1.5	.,	
Minimum V _I for valid PG	I _{PG} = 300 μA I _{PG} = 300 μA		-40°C to 125°C			1.9	- V	

[†]CSR (compensation series resistance) refers to the total series resistance, including the equivalent series resistance (ESR) of the capacitor, any series resistance added externally, and PWB trace resistance to CO.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.



TPS7101 electrical characteristics at I_O = 10 mA, V_I = 3.5 V, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , FB shorted to OUT at device leads (unless otherwise noted)

	TEST CONDITIONS [‡]		т.	TPS7101Q			UNIT	
PARAMETER	TEST CO	NDITIONS+	Тј	MIN	TYP	MAX		
Deference veltage (massived at ED	VI = 3.5 V,	I _O = 10 mA	25°C		1.178		V	
Reference voltage (measured at FB with OUT connected to FB)	2.5 V \leq V _I \leq 10 V, See Note 1	5 mA \leq I _O \leq 500 mA,	-40°C to 125°C	1.143		1.213	V	
Reference voltage temperature coefficient			-40°C to 125°C		61	75	ppm/°C	
	V(- 0.4.V)	50 ··· A < la < 150 mA	25°C		0.7	1		
	V _I = 2.4 V,	$50 \ \mu A \le I_O \le 150 \ mA$	-40°C to 125°C			1		
	$V_1 = 2.4 V_1$	$150 \text{ mA} \le I_{O} \le 500$	25°C		0.83	1.3		
Pass-element series resistance	$v_{\parallel} = 2.4 v_{,}$	mA	-40°C to 125°C			1.3	Ω	
(see Note 2)	V ₁ = 2.9 V,	$50 \ \mu A \le I_O \le 500 \ mA$	25°C		0.52	0.85		
	v] = 2.9 v,	$50 \ \mu\text{A} \le 10 \le 500 \ \text{MA}$	-40°C to 125°C			0.85		
	V _I = 3.9 V,	$50 \ \mu A \le I_O \le 500 \ mA$	25°C		0.32			
	V _I = 5.9 V,	$50 \ \mu A \leq I_{O} \leq 500 \ mA$	25°C		0.23			
	VI = 2.5 V to 10 V,	50 μ A \leq I _O \leq 500 mA,	25°C			18	mV	
Input regulation	See Note 1		-40°C to 125°C			25		
Output regulation	$I_{O} = 5 \text{ mA to } 500 \text{ mA},$	$2.5 \text{ V} \le \text{V}_{I} \le 10 \text{ V},$	25°C			14	mV	
	See Note 1		-40°C to 125°C			25		
Output regulation	$I_{O} = 50 \ \mu A$ to 500 mA, See Note 1	$2.5 \text{ V} \leq \text{V}_{I} \leq 10 \text{ V},$	25°C			22	mV	
			-40°C to 125°C			54		
		I _O = 50 μA	25°C	48	59		dB	
Ripple rejection	f = 120 Hz		-40°C to 125°C	44				
	1 - 120112	I _O = 500 mA,	25°C	45	54			
		See Note 1	-40°C to 125°C	44				
Output noise-spectral density	f = 120 Hz		25°C		2		μV/√Hz	
		C _O = 4.7 μF	25°C		95			
Output noise voltage	10 Hz ≤ f ≤ 100 kHz, CSR [†] = 1 Ω	C _O = 10 μF	25°C		89		μVrms	
	0010 - 1 32	C _O = 100 μF	25°C		74			
PG trip-threshold voltage§	VFB voltage decreasing	g from above V _{PG}	-40°C to 125°C	1.101		1.145	V	
PG hysteresis voltage§	Measured at VFB		25°C		12		mV	
			25°C		0.1	0.4		
PG output low voltage§	I _{PG} = 400 μA,	V _I = 2.13 V	-40°C to 125°C			0.4	V	
			25°C	-10	0.1	10		
FB input current			-40°C to 125°C	-20		20	nA	

[†]CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Output voltage programmed to 2.5 V with closed-loop configuration (see application information).

NOTES: 1. When V_I < 2.9 V and I_O > 150 mA simultaneously, pass element r_{DS(on)} increases (see Figure 27) to a point such that the resulting dropout voltage prevents the regulator from maintaining the specified tolerance range.

2. To calculate dropout voltage, use equation:

 $V_{DO} = I_O \cdot r_{DS(on)}$

 $r_{DS(on)}$ is a function of both output current and input voltage. The parametric table lists $r_{DS(on)}$ for V_I = 2.4 V, 2.9 V, 3.9 V, and 5.9 V, which corresponds to dropout conditions for programmed output voltages of 2.5 V, 3 V, 4 V, and 6 V, respectively. For other programmed values, refer to Figure 26.



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TPS7133 electrical characteristics at I_O = 10 mA, V_I = 4.3 V, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , SENSE shorted to OUT (unless otherwise noted)

	TEST CONDITIONS [‡]		-	TPS7133Q			
PARAMETER	TEST CON	IDITIONS+	Тј	MIN	TYP	MAX	UNIT
Outractionships	V _I = 4.3 V,	I _O = 10 mA	25°C		3.3		v
Output voltage	$4.3 \text{ V} \le \text{V}_{I} \le 10 \text{ V},$	$5 \text{ mA} \le \text{IO} \le 500 \text{ mA}$	-40°C to 125°C	3.23		3.37	v
	1- 10	V _I = 3.23 V	25°C		4.5	7	
	I _O = 10 mA,		-40°C to 125°C			8	
Description	I _O = 100 mA,	V/- 2 22 V/	25°C		47	60	mV
Dropout voltage		V _I = 3.23 V	-40°C to 125°C			80	mv
	la 500 mA	V/- 2 22 V/	25°C		235	300	
	I _O = 500 mA,	V _I = 3.23 V	-40°C to 125°C			400	
Pass-element series resistance	(3.23 V – V _O)/I _O ,	V _I = 3.23 V,	25°C		0.47	0.6	Ω
Pass-element series resistance	I _O = 500 mA	-	-40°C to 125°C			0.8	.8 52
Law of the mode Care	V ₁ = 4.3 V to 10 V,	$50 \ \mu A \le I_{O} \le 500 \ mA$	25°C			20	mV
Input regulation	$v_{\rm I} = 4.3 v 10 10 v,$		-40°C to 125°C			27	mv
	I _O = 5 mA to 500 mA,	$4.3~V \le V_I \le 10~V$	25°C		21	38	mV
			-40°C to 125°C			75	mv
Output regulation	10 - 50 + 4 + 500 - 500	, 4.3 V ≤ V _I ≤ 10 V	25°C		30	60	mV
	$10 = 30 \mu \text{A} \text{ to } 300 \text{mA},$		-40°C to 125°C			120	
		I _O = 50 μA	25°C	43	54		dB
Ripple rejection	f = 120 Hz		-40°C to 125°C	40			
	1 = 120112	I _O = 500 mA	25°C	39	49		UD UD
		10 = 300 IIIA	-40°C to 125°C	36			
Output noise-spectral density	f = 120 Hz		25°C		2		μV/√Hz
		C _O = 4.7 μF	25°C		274		
Output noise voltage	10 Hz ≤ f ≤ 100 kHz, CSR [†] = 1 Ω	C _O = 10 μF	25°C		228		μVrms
	001(1 = 1 52	C _O = 100 μF	25°C		159		
PG trip-threshold voltage	VO voltage decreasing	φ .	-40°C to 125°C	2.868		3	V
PG hysteresis voltage			25°C		35		mV
	1 4	N 0.0.V	25°C		0.22	0.4	
PG output low voltage	I _{PG} = 1 mA,	V _I = 2.8 V	-40°C to 125°C			0.4	V

† CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to CO.

[‡]Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.



TPS7148 electrical characteristics at $I_0 = 10 \text{ mA}$, $V_1 = 5.85 \text{ V}$, $\overline{\text{EN}} = 0 \text{ V}$, $C_0 = 4.7 \,\mu\text{F/CSR}^{\dagger} = 1 \,\Omega$, SENSE shorted to OUT (unless otherwise noted)

PARAMETER	TEST CON		т.	TF	PS71480	2	UNIT
PARAMETER	TEST CON	IDITIONS+	Тј	MIN	TYP	MAX	
Output voltogo	VI = 5.85 V,	I _O = 10 mA	25°C		4.85		v
Output voltage	5.85 V \leq V _I \leq 10 V,	$5 \text{ mA} \le \text{IO} \le 500 \text{ mA}$	-40°C to 125°C	4.75		4.95	ľ
	40 40	V _I = 4.75 V	25°C		2.9	6	
	I _O = 10 mA,		-40°C to 125°C			8	1
Description	I _O = 100 mA,	\/. 47E\/	25°C		30	37	mV
Dropout voltage		V _I = 4.75 V	-40°C to 125°C			54	
	la 500 mA	\/. 47E\/	25°C		150	180	1
	I _O = 500 mA,	V _I = 4.75 V	-40°C to 125°C			250	1
	(4.75 V – V _O)/I _O ,	V _I = 4.75 V,	25°C		0.32	0.35	
Pass-element series resistance	$I_{O} = 500 \text{ mA}$		-40°C to 125°C			0.52	Ω
Input regulation		$50 \ \mu A \leq I_{O} \leq 500 \ mA$	25°C			27	m∨
	$V_{I} = 5.85 V \text{ to } 10 V,$		-40°C to 125°C			37	
	I _O = 5 mA to 500 mA,	$5.85~V \leq V_{I} \leq 10~V$	25°C		12	42	mV
			-40°C to 125°C			80	
Output regulation		5.85 V \leq VJ \leq 10 V	25°C		42	60	mV
	$10 = 50 \mu A \ 10 \ 500 \mu A$		-40°C to 125°C			130	
		I _O = 50 μA	25°C	42	53		
Dipple rejection	f = 120 Hz		-40°C to 125°C	39			
Ripple rejection	1 = 120 HZ	La 500 mA	25°C	39	50		dB
		I _O = 500 mA	-40°C to 125°C	35			1
Output noise-spectral density	f = 120 Hz		25°C		2		μV/√Hz
		C _O = 4.7 μF	25°C		410		
Output noise voltage	10 Hz ≤ f ≤ 100 kHz, CSR [†] = 1 Ω	C _O = 10 μF	25°C		328		μVrms
		C _O = 100 μF	25°C		212		1
PG trip-threshold voltage	VO voltage decreasing	-	-40°C to 125°C	4.5		4.7	V
PG hysteresis voltage			25°C		50		mV
	1 10 mA	<u> </u>	25°C		0.2	0.4	v
PG output low voltage	IPG = 1.2 mA,	V _I = 4.12 V	-40°C to 125°C			0.4	V

[†]CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.

[‡] Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.



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TPS7150 electrical characteristics at I_O = 10 mA, V_I = 6 V, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , SENSE shorted to OUT (unless otherwise noted)

	TEAT OOL	TEST CONDITIONS [‡]		TF	PS71500	ג	
PARAMETER	TEST CON			MIN	TYP	MAX	UNIT
Output usite as	V _I = 6 V,	I _O = 10 mA	25°C		5		v
Output voltage	$6 \text{ V} \leq \text{V}_{I} \leq 10 \text{ V},$	$5 \text{ mA} \le \text{IO} \le 500 \text{ mA}$	-40°C to 125°C	4.9		5.1	
	1- 10	V _I = 4.88 V	25°C		2.9	6	
	I _O = 10 mA,		-40°C to 125°C			8	1
	I _O = 100 mA,	\/. 4 00 \/	25°C		27	32	mV
Dropout voltage		V _I = 4.88 V	-40°C to 125°C			47	
	la 500 mA	V/. 4.00 V/	25°C		146	170	1
	I _O = 500 mA,	VI = 4.88 V	-40°C to 125°C			230	1
	(4.88 V – V _O)/I _O ,	VI = 4.88 V,	25°C		0.29	0.32	Ω
Pass-element series resistance	$I_{O} = 500 \text{ mA}$	-	-40°C to 125°C			0.47	7
	$V_{I} = 6 V \text{ to } 10 V,$	$50~\mu A \leq I_{O} \leq 500~mA$	25°C			25	mV
Input regulation	$v_{\rm I} = 0 v to 10 v,$		-40°C to 125°C			32	IIIV
	I _O = 5 mA to 500 mA,	$6 V \le V_I \le 10 V$ $6 V \le V_I \le 10 V$	25°C		30	45	mV
			-40° C to 125° C			86	IIIV
Output regulation	$h_{0} = 50 \text{ m} \text{ A}$ to $500 \text{ m} \text{ A}$		25°C		45	65	- mV
	$10 = 50 \mu A 10 500 \text{mA},$		-40° C to 125° C			140	
		I _O = 50 μA	25°C	45	55		dB
Ripple rejection	f = 120 Hz		-40° C to 125° C	40			
	1 = 120112	I _O = 500 mA	25°C	42	52		uв
		IO = 300 IIIA	-40° C to 125° C	36			
Output noise-spectral density	f = 120 Hz		25°C		2		μV/√Hz
		C _O = 4.7 μF	25°C		430		
Output noise voltage	10 Hz ≤ f ≤ 100 kHz, CSR [†] = 1 Ω	C _O = 10 μF	25°C		345		μVrms
	001(1 = 1 22	C _O = 100 μF	25°C		220		1
PG trip-threshold voltage	VO voltage decreasing	•	-40°C to 125°C	4.55		4.75	V
PG hysteresis voltage			25°C		53		mV
-			25°C		0.2	0.4	.,
PG output low voltage	I _{PG} = 1.2 mA,	V _I = 4.25 V	-40°C to 125°C			0.4	V

† CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to CO.

[‡]Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.



electrical characteristics at I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , T_J = 25°C, SENSE/FB shorted to OUT (unless otherwise noted)

PARAMETER	TEST CONDITIONS [‡]	TPS7101Y, TPS7133Y TPS7148Y, TPS7150Y	UNIT
		MIN TYP MAX	
Ground current (active mode)	$\label{eq:loss} \begin{array}{ll} \overline{\text{EN}} \leq 0.5 \text{ V}, & \text{V}_I = \text{V}_O + 1 \text{ V}, \\ 0 \text{ mA} \leq I_O \leq 500 \text{ mA} \end{array}$	285	μA
Output current limit	$V_{O} = 0,$ $V_{I} = 10 V$	1.2	А
PG leakage current	Normal operation, $V_{PG} = 10 V$	0.02	μA
Thermal shutdown junction temperature		165	°C
EN hysteresis voltage		50	mV
Minimum VI for active pass element		2.05	V
Minimum V _I for valid PG	I _{PG} = 300 μA	1.06	V

PARAMETER	TEAT OF	T	· · · · · · · · · · · · · · · · · · ·			
PARAMETER	TEST CO	TEST CONDITIONS [‡]				UNIT
Reference voltage (measured at FB with OUT connected to FB)	V _I = 3.5 V,	I _O = 10 mA		1.178		V
	V _I = 2.4 V,	$50 \ \mu A \le I_O \le 150 \ mA$		0.7		
	V _I = 2.4 V,	$150~mA \le I_{O} \le 500~mA$		0.83		
Pass-element series resistance (see Note 2)	V _I = 2.9 V,	$50 \ \mu A \le I_O \le 500 \ mA$		0.52		Ω
	V _I = 3.9 V,	$50 \ \mu A \leq I_O \leq 500 \ mA$		0.32		
	V _I = 5.9 V,	$50 \ \mu A \leq I_O \leq 500 \ mA$		0.23		
Input regulation	V _I = 2.5 V to 10 V, See Note 1	50 $\mu A \leq I_{O} \leq$ 500 mA,			18	mV
	$2.5 V \le V_I \le 10 V$, See Note 1	I _O = 5 mA to 500 mA,			14	mV
Output regulation	$2.5 V \le V_I \le 10 V$, See Note 1	$I_{O} = 50 \ \mu A \text{ to } 500 \ m A,$			22	mV
Ripple rejection	V _I = 3.5 V, I _O = 50 μA	f = 120 Hz,		59		dB
Output noise-spectral density	V _I = 3.5 V,	f = 120 Hz		2		μV/√Hz
	V _I = 3.5 V,	C _O = 4.7 μF		95		
Output noise voltage	$10 \text{ Hz} \le \text{f} \le 100 \text{ kHz},$	C _O = 10 μF		89		μVrms
	$CSR^{\dagger} = 1 \Omega$	C _O = 100 μF	74			
PG hysteresis voltage§	V _I = 3.5 V,	Measured at V _{FB}		12		mV
PG output low voltage§	V _I = 2.13 V,	I _{PG} = 400 μA		0.1		V
FB input current	VI = 3.5 V	VI = 3.5 V		0.1		nA

† CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to C_O.

[‡]Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

§ Output voltage programmed to 2.5 V with closed-loop configuration (see application information).

NOTES: 1. When VI < 2.9 V and IO > 150 mA simultaneously, pass element rDS(on) increases (see Figure 27) to a point such that the resulting dropout voltage prevents the regulator from maintaining the specified tolerance range.

2. To calculate dropout voltage, use equation:

 $V_{DO} = I_O \cdot r_{DS(on)}$

rDS(on) is a function of both output current and input voltage. The parametric table lists rDS(on) for VI = 2.4 V, 2.9 V, 3.9 V, and 5.9 V, which corresponds to dropout conditions for programmed output voltages of 2.5 V, 3 V, 4 V, and 6 V, respectively. For other programmed values, refer to Figure 26.



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electrical characteristics at I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , T_J = 25°C, SENSE shorted to OUT (unless otherwise noted) (continued)

DADAMETED	TEAT AS		TP				
PARAMETER	TEST CC	TEST CONDITIONS [‡]				UNIT	
Output voltage	V _I = 4.3 V,	l _O = 10 mA		3.3		V	
	V _I = 3.23 V,	I _O = 10 mA		0.02			
Dropout voltage	V _I = 3.23 V,	I _O = 100 mA		47		mV	
	V _I = 3.23 V,	I _O = 500 mA		235			
Pass-element series resistance	$(3.23 V - V_O)/I_O,$ $I_O = 500 \text{ mA}$					Ω	
	4.3 V \leq V _I \leq 10 V,	I _O = 5 mA to 500 mA		21		mV	
Output regulation	$4.3 \text{ V} \le \text{V}_{I} \le 10 \text{ V},$	$I_{O} = 50 \ \mu A$ to 500 mA		30		mV	
Disple rejection	V _I = 4.3 V,	I _O = 50 μA	54 49		dB		
Ripple rejection	f = 120 Hz	I _O = 500 mA			uБ		
Output noise-spectral density	V _I = 4.3 V,	f = 120 Hz		2		μV/√Hz	
	V _I = 4.3 V,	C _O = 4.7 μF	274 228 159			μVrms	
Output noise voltage	10 Hz \leq f \leq 100 kHz,	C _O = 10 μF					
	$CSR^{\dagger} = 1 \Omega$	C _O = 100 μF					
PG hysteresis voltage	V _I = 4.3 V	-		35		mV	
PG output low voltage	V _I = 2.8 V,	I _{PG} = 1 mA		0.22		V	

	TEAT OF	TP				
PARAMETER	TEST CO	TEST CONDITIONS [‡]				UNIT
Output voltage	Vj = 5.85 V,	I _O = 10 mA		4.85		V
	V _I = 4.75 V,	I _O = 10 mA		0.08		
Dropout voltage	V _I = 4.75 V,	I _O = 100 mA		30		mV
	V _I = 4.75 V,	IO = 500 mA		150		1
Pass-element series resistance	(4.75 V – V _O)/I _O , I _O = 500 mA					Ω
	5.85 V ≤ V _I ≤ 10 V,	IO = 5 mA to 500 mA		12		mV
Output regulation	5.85 V \leq V _I \leq 10 V,	I_{O} = 50 μ A to 500 mA		42		mV
Divide rejection	V _I = 5.85 V,	I _O = 50 μA	53 50			- ID
Ripple rejection	f = 120 Hz	I _O = 500 mA				dB
Output noise-spectral density	V _I = 5.85 V,	f = 120 Hz		2		μV/√Hz
	V _I = 5.85 V,	C _O = 4.7 μF		410		
Output noise voltage	$10 \text{ Hz} \le \text{f} \le 100 \text{ kHz},$	C _O = 10 μF	328 212			μVrms
	$CSR^{\dagger} = 1 \Omega$	C _O = 100 μF			1	
PG hysteresis voltage	V _I = 5.85 V	-		50		mV
PG output low voltage	V _I = 4.12 V,	I _{PG} = 1.2 mA		0.2	0.4	V

† CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to CO.

[‡]Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.



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electrical characteristics at I_O = 10 mA, \overline{EN} = 0 V, C_O = 4.7 μ F/CSR[†] = 1 Ω , T_J = 25°C, SENSE shorted to OUT (unless otherwise noted) (continued)

			TF	<u>-</u>		
PARAMETER	TESTC	TEST CONDITIONS [‡]				UNIT
Output voltage	V _I = 6 V,	I _O = 10 mA		5		V
	V _I = 4.88 V,	I _O = 10 mA		0.13		
Dropout voltage	V _I = 4.88 V,	I _O = 100 mA		27		mV
	V _I = 4.88 V,	I _O = 500 μA		146		
Pass-element series resistance	$(4.88 V - V_O)/I_O,$ $I_O = 500 mA$	V _I = 4.88 V,		0.29		Ω
	6 V ≤ V _I ≤ 10 V,	I _O = 5 mA to 500 mA	30			mV
Output regulation	$6 V \le V_I \le 10 V$,	I_{O} = 50 μ A to 500 mA		45		mV
	V _I = 6 V,	IO = 50 μA		55		dB
Ripple rejection	f = 120 Hz	I _O = 500 mA		52		uв
Output noise-spectral density	V _I = 6 V,	f = 120 Hz		2		μV/√ Hz
	VI = 6 V,	C _O = 4.7 μF	430			
Output noise voltage	10 Hz ≤ f ≤ 100 kHz,	C _O = 10 μF		345		μVrms
	$CSR^{\dagger} = 1 \Omega$	C _O = 100 μF		220		
PG hysteresis voltage	V _I = 6 V	-		53		mV
PG output low voltage	V _I = 4.25 V,	PG = 1.2 mA		0.2		V

[†]CSR refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to CO.

[‡]Pulse-testing techniques are used to maintain virtual junction temperature as close as possible to ambient temperature; thermal effects must be taken into account separately.

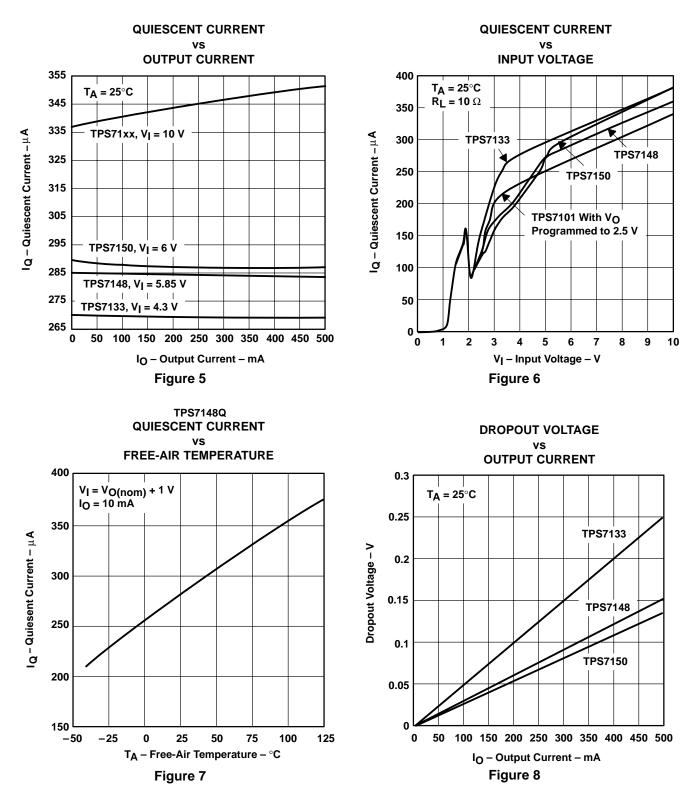


TYPICAL CHARACTERISTICS

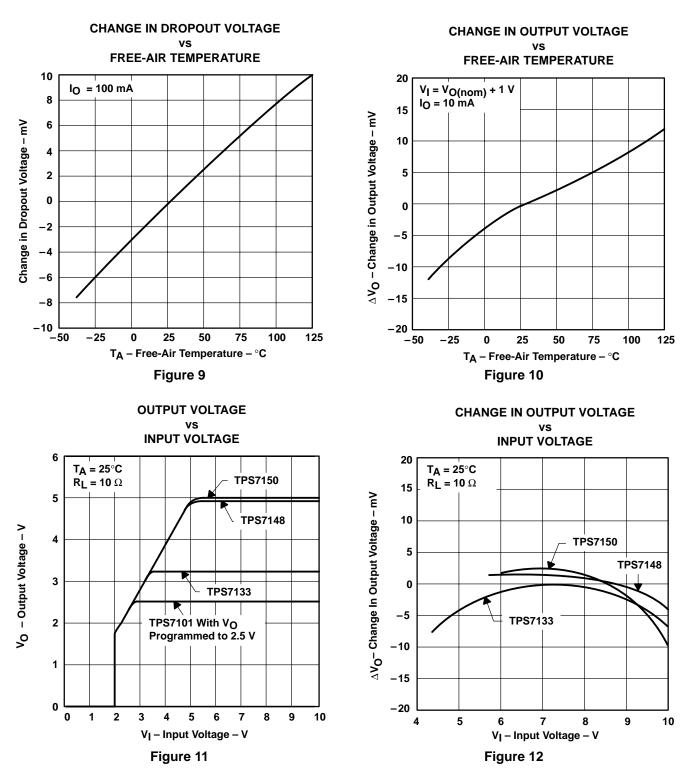
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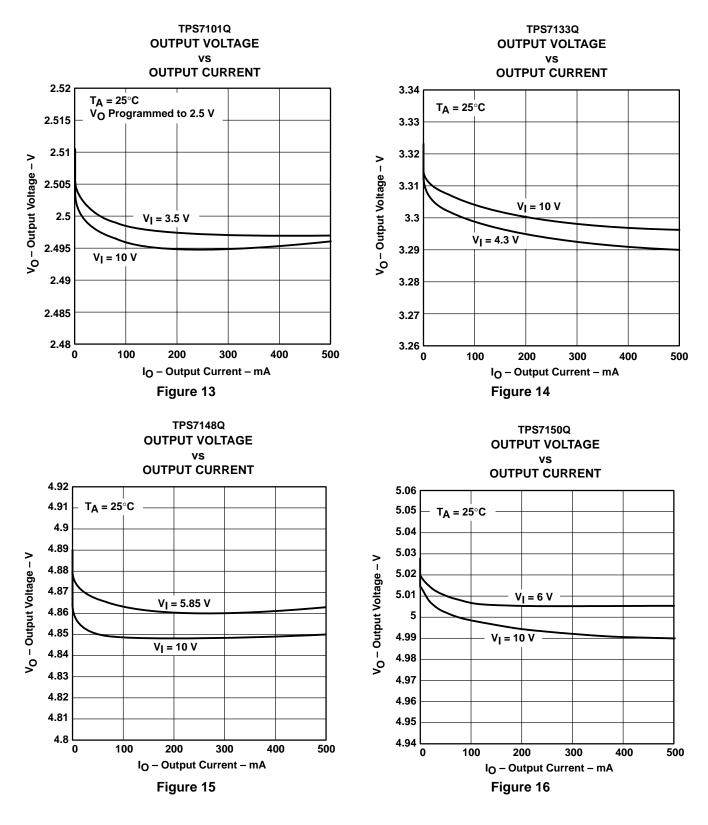






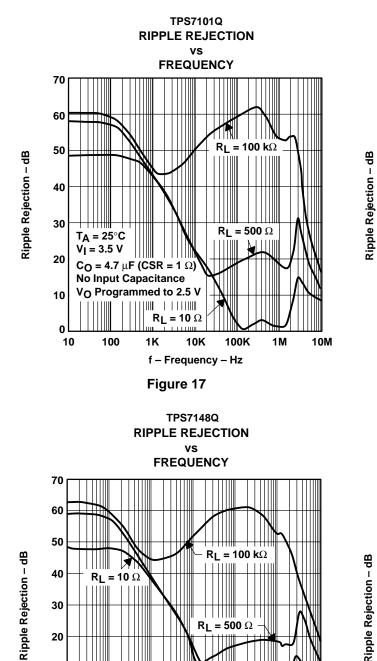


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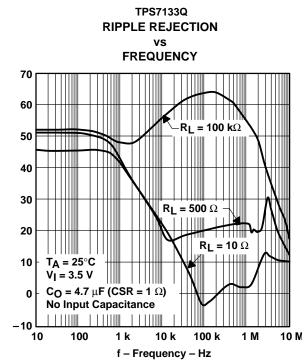
TYPICAL CHARACTERISTICS



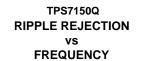
R_I = 500 Ω

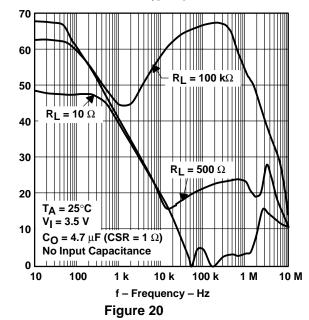
100 k

1 M











10 M

30

20

10

0

-10

10

= 25°C T۵

= 3.5 V

100

1.1.1.1.00

 $C_0 = 4.7 \ \mu F (CSR = 1 \ \Omega)$

No Input Capacitance

1.1.1.1.00

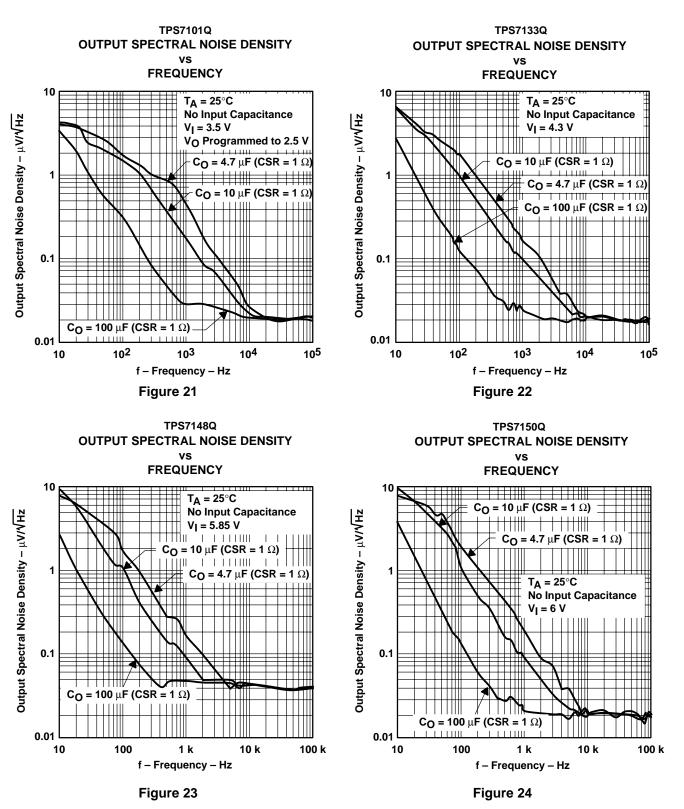
1 k

1.1.1.111

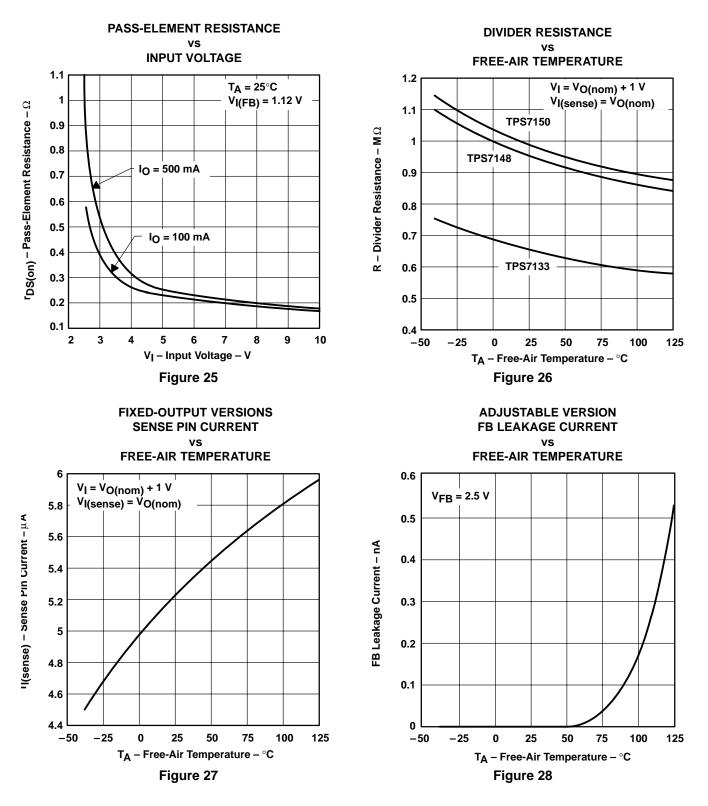
Figure 19

10 k

f - Frequency - Hz

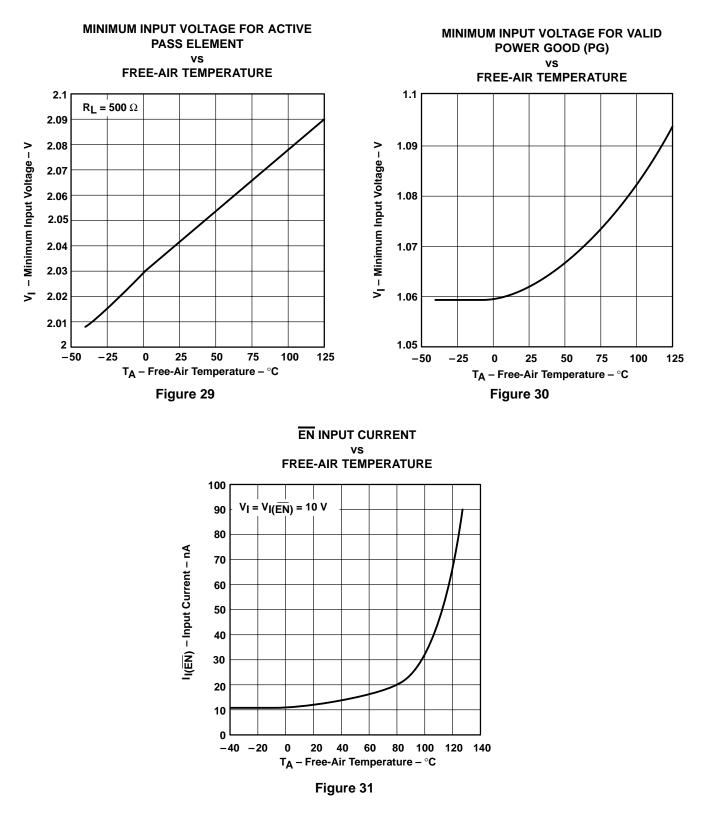








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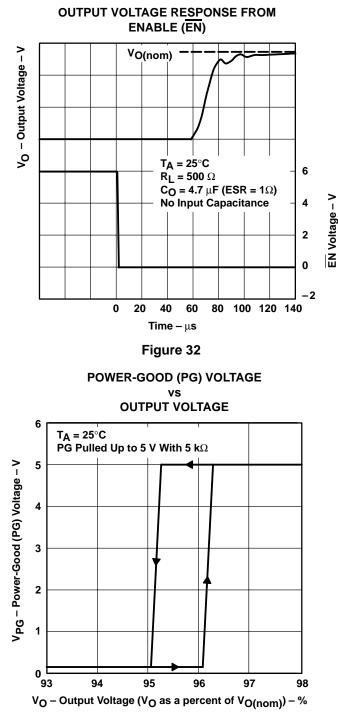
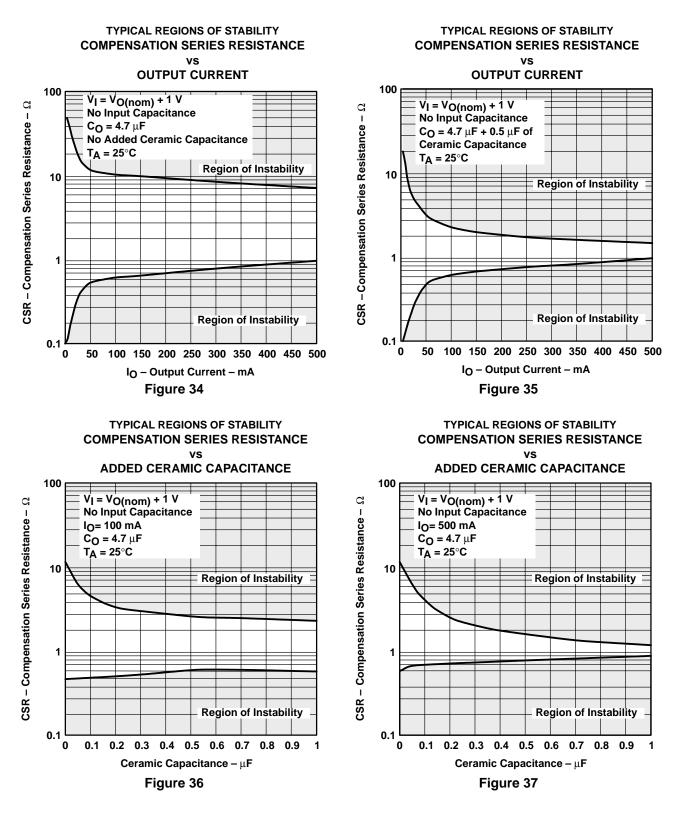


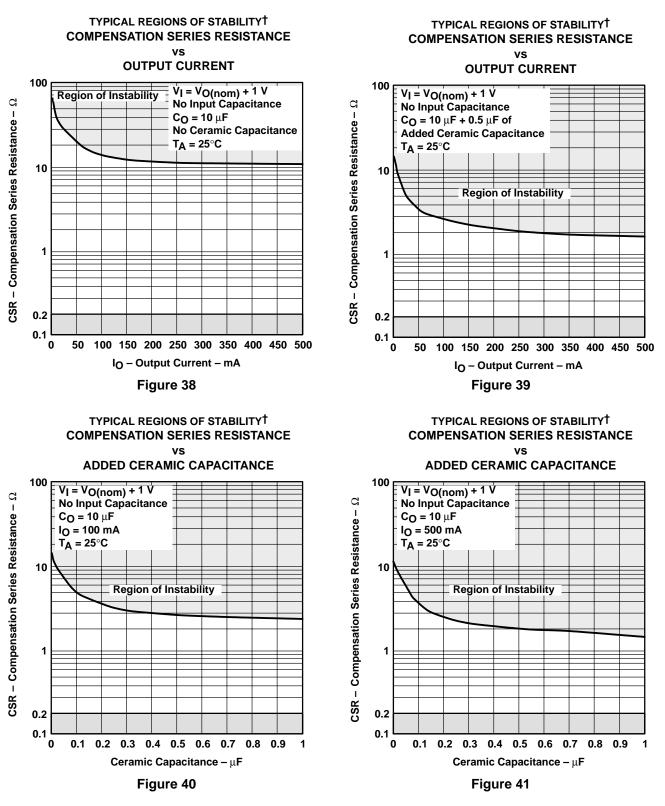
Figure 33







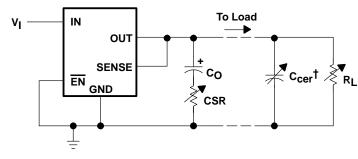
TYPICAL CHARACTERISTICS



 \dagger CSR values below 0.1 Ω are not recommended.



TYPICAL CHARACTERISTICS



[†]Ceramic capacitor





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APPLICATION INFORMATION

The TPS71xx series of low-dropout (LDO) regulators is designed to overcome many of the shortcomings of earlier-generation LDOs, while adding features such as a power-saving shutdown mode and a power-good indicator. The TPS71xx family includes three fixed-output voltage regulators: the TPS7133 (3.3 V), the TPS7148 (4.85 V), and the TPS7150 (5 V). The family also offers an adjustable device, the TPS7101 (adjustable from 1.2 V to 9.75 V).

device operation

The TPS71xx, unlike many other LDOs, features very low quiescent currents that remain virtually constant even with varying loads. Conventional LDO regulators use a pnp-pass element, the base current of which is directly proportional to the load current through the regulator ($I_{\rm B} = I_{\rm C}/\beta$). Close examination of the data sheets reveals that those devices are typically specified under near no-load conditions; actual operating currents are much higher as evidenced by typical quiescent current versus load current curves. The TPS71xx uses a PMOS transistor to pass current; because the gate of the PMOS element is voltage driven, operating currents are low and invariable over the full load range. The TPS71xx specifications reflect actual performance under load.

Another pitfall associated with the pnp-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS71xx guiescent current remains low even when the regulator drops out, eliminating both problems.

Included in the TPS71xx family is a 4.85-V regulator, the TPS7148. Designed specifically for 5-V cellular systems, its 4.85-V output, regulated to within \pm 2%, allows for operation within the low-end limit of 5-V systems specified to \pm 5% tolerance; therefore, maximum regulated operating lifetime is obtained from a battery pack before the device drops out, adding crucial talk minutes between charges.

The TPS71xx family also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to under 2 µA. If the shutdown feature is not used. EN should be tied to ground. Response to an enable transition is guick; regulated output voltage is reestablished in typically 120 µs.

minimum load requirements

The TPS71xx family is stable even at zero load; no minimum load is required for operation.

SENSE-pin connection

The SENSE pin of fixed-output devices must be connected to the regulator output for proper functioning of the regulator. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit (remote sense) to improve performance at that point. Internally, SENSE connects to a high-impedance wide-bandwidth amplifier through a resistor-divider network and noise pickup feeds through to the regulator output. Routing the SENSE connection to minimize/avoid noise pickup is essential. Adding an RC network between SENSE and OUT to filter noise is not recommended because it can cause the regulator to oscillate.

external capacitor requirements

An input capacitor is not required; however, a ceramic bypass capacitor (0.047 pF to 0.1 μ F) improves load transient response and noise rejection if the TPS71xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

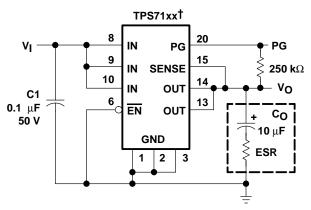


APPLICATION INFORMATION

external capacitor requirements (continued)

As with most LDO regulators, the TPS71xx family requires an output capacitor for stability. A $10-\mu$ F solid-tantalum capacitor connected from the regulator output to ground is sufficient to ensure stability over the full load range (see Figure 43). Adding high-frequency ceramic or film capacitors (such as power-supply bypass capacitors for digital or analog ICs) can cause the regulator to become unstable unless the ESR of the tantalum capacitor is less than 1.2 Ω over temperature. Where component height and/or mounting area is a problem, physically smaller, $10-\mu$ F devices can be screened for ESR. Figures 34 through 41 show the stable regions of operation using different values of output capacitance with various values of ceramic load capacitance.

In applications with little or no high-frequency bypass capacitance (< 0.2μ F), the output capacitance can be reduced to 4.7 μ F, provided ESR is maintained between the values shown in figures 34 through 41. Because minimum capacitor ESR is seldom if ever specified, it may be necessary to add a $0.5-\Omega$ to $1-\Omega$ resistor in series with the capacitor and limit ESR to 1.5Ω maximum.



[†] TPS7133, TPS7148, TPS7150 (fixed-voltage options)

Figure 43. Typical Application Circuit

programming the TPS7101 adjustable LDO regulator

Programming the adjustable regulators is accomplished using an external resistor divider as shown in Figure 44. The equation governing the output voltage is:

$$V_{O} = V_{ref} \cdot \left(1 + \frac{R1}{R2}\right)$$

where

V_{ref} = reference voltage, 1.178 V typ



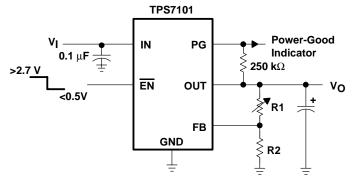
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APPLICATION INFORMATION

programming the TPS7101 adjustable LDO regulator (continued)

Resistors R1 and R2 should be chosen for approximately 7-µA divider current. A recommended value for R2 is 169 k Ω with R1 adjusted for the desired output voltage. Smaller resistors can be used, but offer no inherent advantage and consume more power. Larger values of R1 and R2 should be avoided as leakage currents at FB introduce an error. Solving equation 1 for R1 yields a more useful equation for choosing the appropriate resistance:

$$R1 = \left(\frac{V_0}{V_{ref}} - 1\right) \cdot R2$$



OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	191	169	kΩ
3.3 V	309	169	kΩ
3.6 V	348	169	kΩ
4 V	402	169	kΩ
5 V	549	169	kΩ
6.4 V	750	169	kΩ



power-good indicator

The TPS71xx features a power-good (PG) output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the PG output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. PG can be used to drive power-on reset circuitry or as a low-battery indicator. PG does not assert itself when the regulated output voltage falls outside the specified 2% tolerance, but instead reports an output voltage low, relative to its nominal regulated value.

regulator protection

The TPS71xx PMOS-pass transistor has a built-in back diode that safely conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS71xx also features internal current limiting and thermal protection. During normal operation, the TPS71xx limits output current to approximately 1 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 165°C, thermal-protection circuitry shuts it down. Once the device has cooled, regulator operation resumes.





PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status	Package Type		Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS7101QD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7101Q	Samples
TPS7101QDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7101Q	Samples
TPS7101QP	ACTIVE	PDIP	Ρ	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-40 to 125	TPS7101QP	Samples
TPS7101QPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PT7101	Samples
TPS7133QD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7133Q	Samples
TPS7133QDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7133Q	Samples
TPS7133QDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7133Q	Samples
TPS7133QDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7133Q	Samples
TPS7133QP	ACTIVE	PDIP	Ρ	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-40 to 125	TPS7133QP	Samples
TPS7148QD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7148Q	Samples
TPS7148QP	ACTIVE	PDIP	Ρ	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-40 to 125	TPS7148QP	Samples
TPS7150QD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7150Q	Samples
TPS7150QDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7150Q	Samples
TPS7150QDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	7150Q	Samples
TPS7150QP	ACTIVE	PDIP	Р	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	-40 to 125	TPS7150QP	Samples

(1) The marketing status values are defined as follows:
 ACTIVE: Product device recommended for new designs.
 LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
 NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



6-Feb-2020

PREVIEW: Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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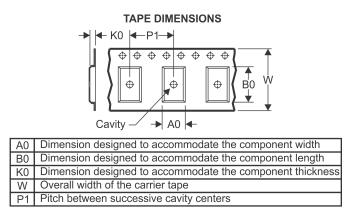
PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7101QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS7101QPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
TPS7133QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TPS7150QDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

16-Oct-2020



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7101QDR	SOIC	D	8	2500	853.0	449.0	35.0
TPS7101QPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
TPS7133QDR	SOIC	D	8	2500	350.0	350.0	43.0
TPS7150QDR	SOIC	D	8	2500	350.0	350.0	43.0

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. β . This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
 C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



D0008A



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.

- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



D0008A

EXAMPLE BOARD LAYOUT

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



D0008A

EXAMPLE STENCIL DESIGN

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



P(R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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